PHOTOCATHODE FEMTOSECOND RF GUN*

J. Yang#, K. Kan, T. Yamamoto, N. Naruse, Y. Yoshida, K. Tanimura, The Institute of Scientific and Industrial Research, Osaka University, 8-1 Mihogaoka, Ibaraki, Osaka 567-0047, Japan

Abstract

A new photocathode-based femtosecond electron source is developed in Osaka University to generate a low-emittance femtosecond-bunch electron for revealing the hidden dynamics of intricate molecular and atomic processes in materials through time-resolved pulse radiolysis and time-resolved electron diffraction. A photocathode rf gun with many improvements was constructed under the KEK/Osaka University collaboration. The transverse and longitudinal dynamics of femtosecond electron beam in the rf gun were studied by particle simulation. The growths of the emittance, bunch length and energy spread due to the rf and space charge effects were investigated by changing the laser parameters and bunch charge. The simulation indicates that a sub-100-fs MeV electron beam with the transverse emittance of 0.1 mm-mrad and the relative energy spread of $10^{-2}$ as bunch charge of 0.1-1 pC is achievable in the rf gun driven by a femtosecond laser light.

INTRODUCTION

High-brightness electron sources, producing short, intense, low-emittance electron bunches, are key elements not only for new developments in accelerator physics, i.e. future electron-positron colliders and x-ray free electron lasers, but also for structure and dynamics research in material science, biology, physics and chemistry. Femtosecond electron bunches of the order of 100 fs are essential to reveal the hidden dynamics of intricate molecular and atomic processes in materials through experimentation such as time-resolved pulse radiolysis, ultrafast electron diffraction (UED) or ultrafast electron microscopy (UEM). In the pulse radiolysis [1], a short electron bunch is used as a pump source. The electron-induced ultrafast reactions are analyzed generally with an ultrashort probe light such as femtosecond lasers. A femtosecond single electron bunch with beam energy from a few to a few tens MeV is very important to be utilized in this technique for observing information of the most basic reaction mechanisms on femtosecond time scale, e.g. excitation, ionization, and relaxation of atoms and molecules.

The UED or UEM provides a unique opportunity for a complete determination of the transient structures with atomic level detail [2]. A 100-fs-long bunch electron beam is essential to measure the ultrafast atomic motions on the fundamental time scale of a single atomic vibrational period (100 fs to ~1 ps) for the study of complex phase transient phenomena in solids, the kinetic pathways of chemical reactions, and the biological functioning processes.

In order to produce such low-emittance and short-bunch electron beams, a technology of laser-driven photocathode rf gun [3-6] has been proposed. The rf gun generates femtosecond electron bunches with femtosecond laser pulses. The dynamics of the femtosecond electron beam in the rf gun was studied by the space-charge tracking code PARMELA.

FEMTOSECOND RF GUN

Figure 1 shows the low-emittance femtosecond-bunch electron generation system. A new 1.6-cell S-band (2856 MHz) rf gun, constructed under the KEK/Osaka University collaboration, is used. At the level of <1 mm-mrad, the normalized emittance can be affected by a number of small contributions like field asymmetries or the thermal emittance of the electrons at the cathode, rather than being dominated by a single effect. In order to reduce field asymmetries, the following improvements were carried out: (1) the laser injection ports were removed; (2) a new turner system was designed and (3) a new injection function of the photocathode was installed as shown in Fig. 1. A copper photocathode is used in the experiment because of the low bunch charge; however, the photocathode is removable. A good-symmetry solenoid magnet was mounted at the exit of the rf gun to compensate the transverse emittance growth due to space charge effect.

The rf gun is driven by a femtosecond Ti:Sapphire laser. In the laser system, the Ti:Sapphire oscillator (Tsunami, produced by Spectra-Physics Co.) is mode-locked with a frequency of 79.33 MHz, the 36th sub-harmonic of the 2856 MHz accelerating rf. The outputs of the oscillator laser pulses are captured by a Pockels cell and amplified up to 1mJ in a regenerative amplifier. The repetition rate of the amplifier is 1 kHz. The amplified pulse is converted to the ultraviolet (UV) light using two nonlinear crystals with the maximum energy of 0.15 mJ. The femtosecond UV light is injected on the cathode surface at an incident angle of approximately 2° along the direction of the electron beam using a prism placed downstream of the gun. The minimum pulse width of the UV light is 170 fs for the 100-fs amplified laser pulse input. The laser shaping of the UV light in the spatial and temporal directions is considered to reduce the space-charge force in the bunch.

*Work supported by Joint Development Research at KEK, and JSPS
# yang@sanken.osaka-u.ac.jp

# yang@sanken.osaka-u.ac.jp

* Work supported by Joint Development Research at KEK, and JSPS

---

* Work supported by Joint Development Research at KEK, and JSPS

---
**FEMTOSECOND BEAM DYNAMICS**

**Effect of Laser Injection Phase**

In the rf gun, the phase compression in the longitudinal phase space occurs at low laser injection phase (launch phase) because the electrons come out the photocathode are non-relativistic. This process has been studied for the generation of a sub-picosecond electron beam [3]. Figure 2 shows the dependence of the bunch length on the laser injection phase. The laser pulse width was 100 fs in rms, the rms spot radius was 1 mm, the peak rf field was 100 MV/m and the bunch charge of 0.1 pC. The simulations were ended at a 1-m distance point away from the cathode without any solenoid fields. The data indicate that the bunch compression due to the rf is occurred at <60°. A 50-fs electron bunch can be generated at 30° with a 100-fs laser injection. The low energy spread also can be obtained at the low laser injection phase because of the phase compression in the longitudinal phase space. There are no large changes on the transverse emittance with changing the injection phase from 20° to 60°.

However, at the low injection phase in the rf gun, the actual electric field (effective electric field) at the cathode decreases. The longitudinal self-field of the electron bunch (i.e. longitudinal space charge force) is dominant in the rf gun. In order to reduce the longitudinal space charge effect, the rf gun should be operated with a high-power rf to increase the electric field, or should be operated at a low bunch charge.

**Effect of Laser Spot Size**

Figure 3 shows the bunch length and the transverse emittance changing with the laser beam spot size. The space-charge effect causes the increase on the bunch length at the small laser spot. On the other hand, the rf effect is dominant at the large laser spot, resulting in the increases of the bunch length and the transverse emittance. The minimum bunch length of 50 fs is achieved at the laser spot radius of 0.7 mm for the laser pulse width of 100 fs at the bunch charge of 0.1 pC. It is depended with the laser pulse width and the bunch charge. In the case, the thermal emittance of the electrons at the cathode is dominant the beam transverse emittance.

In order to reduce the thermal emittance, a copper cathode was used in the rf gun, because the work function of the copper is near the UV light energy. The thermal
emittance of the order of 0.1 mm-mrad is achievable by reducing the laser beam size or the effective electric field at the cathode.

**Effect of Laser Pulse Width**

Figure 4 gives the effect of the bunch length, the energy spread and the transverse emittance on the laser pulse width. The bunch length of the electrons increases linearly with the laser pulse width at 0.1 pC. The bunch is compressed to be two factors comparing with the input laser pulse because of the injection of 30° used. A 100-fs electron bunch can be generated in the rf gun with a 200-fs laser pulse injection. The slight increase on the transverse emittance with the laser pulse width is caused by the rf effect.

![Figure 4: Bunch length and normalized transverse emittance versus laser pulse width.](image)

**Dependence on Bunch Charge**

If increase the bunch charge from 0 to 2 pC, the bunch length is only increased from 50 to 70 fs, but the transverse emittance and the energy spread increase largely with the bunch charge due to the space-charge effect, as shown in Fig. 5. In UED or UEM, the ultralow energy spread beam is required. The bunch charge of 1 pC is suitable for the generation of a sub-100-fs electron beam with the relative energy spread of 0.05%, and 0.1 pC for the generation of a femtosecond beam with the energy spread of 0.01%.

![Figure 5: Normalized transverse emittance, bunch length and energy spread versus bunch charge.](image)

**Dependence on Acceleration Field Gradient**

In UED or UEM, a low-energy electron beam is suitable for the diffraction measurement. The beam energy generated in the rf gun can be varied by adjusting the acceleration field gradient. However, the large growths of the bunch length, the emittance and the energy spread are occurred with decreasing the field gradient because of the space-charge effect. To reduce the growths, it would be selected a low bunch charge. As given in Fig. 6, a low-emittance electron beam with charge of 0.1 pC, beam energy of 2 MeV, bunch length of 100 fs and energy spread of 0.03% is achievable in the rf gun.

![Figure 6: Normalized transverse emittance, bunch length and energy spread versus beam energy.](image)

**CONCLUSION**

A photocathode-based low-emittance femtosecond-bunch electron source was reported. The femtosecond beam dynamics in the rf gun was studied by particle simulation. The data indicates that a sub-100-fs MeV electron source with the normalized emittance of 0.1 mm-mrad and the relative energy spread of $10^{-3}$~$10^{-4}$ at bunch charge of 0.1~1 pC is achievable in the photocathode rf gun driven by a femtosecond laser light.

The produced femtosecond electron beam is able to be used in the time-resolved ultrafast electron diffraction for observing information of the most basic mechanisms on the femtosecond time scale. It is a powerful candidate to improve the time-resolution of UED or UEM into ~100 fs time region.

**REFERENCES**